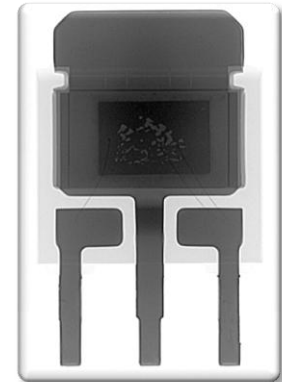


# JCS4N65V

N-Channel MOSFET



Basic

## Product Analysis Report

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To Know

